PNP/NPN Epitaxial Planar Silicon Transistors



CPH6104/CPH6204

High-Current Switching Applications

Applications

· DC-DC converter, relay drivers, lamp drivers, motor drivers, strobes.

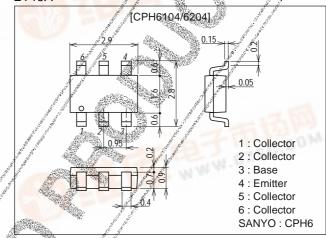
Features

- · Adoption of FBET, MBIT processes.
- · High current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High-speed switching.
- · Ultrasmall package permitting applied sets to be made small and slim (0.9mm).
- · High allowable power dissipation.

Package Dimensions

unit:mm

2146A



(): CPH6104

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Par All All	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage		V _{СВО}	A. W. M. 11	(-)15	V
Collector-to-Emitter Voltage		VCEO		(-)15	V
Emitter-to-Base Voltage		VEBO		(-)5	V
Collector Current		∄ ∌ lc		(-)1.5	Α
Collector Current (Pulse)	S. F. C.	ICP		(-)3	Α
Base Current	gal and	l B		(-)200	mA
Collector Dissipation	1/1/	[₽] C →	Mounted on a ce <mark>ramic board (600mm²×0.8m</mark> m)	1.3	W
Junction Temperature	13	√. Tj		150	°C
Storage Temperature	11 -	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Talaneter	Symbol	of Conditions	min	typ	max	Offic	
Collector Cutoff Current	I _{CBO} //	V _{CB} =(-)12V, I _E =0			(-)100	nA	
Emitter Cutoff Current	I _{EBO} .	V _{EB} =(-)4V, I _C =0			(-)100	nA	
DC Current Gain	hFB1	V _{CE} =(-)2V, I _C =(-)50mA	200	-11	560	40.	
1 1 10 m NG	∕h∉E2	V _{CE} =(-)2V, I _C =(-)800mA	80	107	90.		
Gain-Bandwidth Product	∫ f⊤	V _{CE} =(-)2V, I _C =(-)50mA	A.	(300)		MHz	
Gain-bandwigth Floudet				200		MHz	
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz		(15)10		pF	

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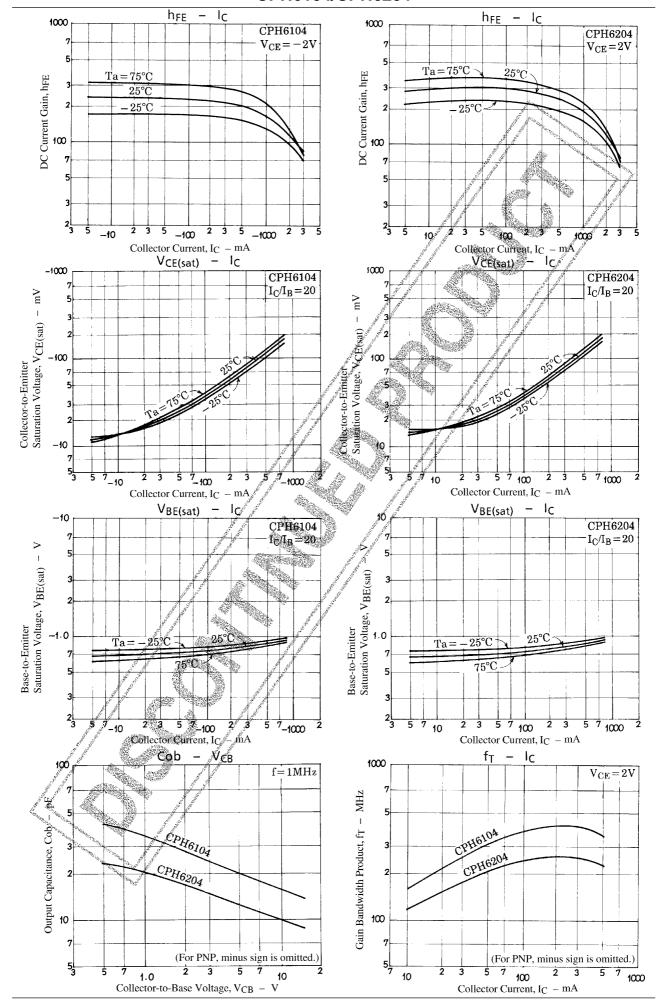


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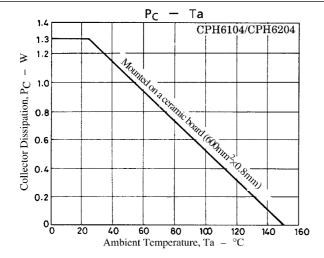
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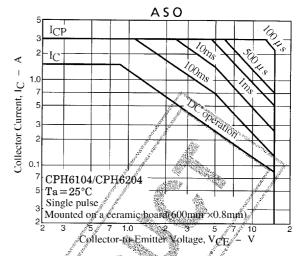
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Parameter	Symbol	Cor	nditions	min	Ratings typ	max	Unit
	V _{CE(sat)} 1	I _C =(-)5mA, I _B =(-)0.5mA			(–)10	(-)25	V
Collector-to-Emitter Saturation Voltage	V _{CE(sat)} ²		(# h)	(-)120	(-)240	V	
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)500mA, I _B =(-)25m	nA	All Marie	(-)0.9	(-)1.2	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)10μΑ, I _E =0		<i>√</i> (-)15	San Marie Barrell	,	V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)1mA, R _{BE} =∞	ži	(–)15	100	Take State of the	V
Emitter-to-Base Breakdown Voltage				(-)5		Search Bridge Street of St	, V
							7
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	CI 6 -0.8 e, VCE - V E CI 2 age VCE -	PH6104 V Tollector Current Tollector Curre	8mA 7mA 6mA 5mA 4mA 2mA 1mA 1mA 1mA 1mA 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt 1collector-to-Emitt	O.G. er Voltage – VCE	see, VCE -	CPH62	1.0
Collector Current, IG		Collector Current, IC		Ta			
-200		0		0.6	0.8	1.0	
0 -0.2 -0.4 -0.6 Base-to-Emitter Voltage	-0.8 -1. e, V _{BE} - V		0 0.2 0.4 Base-to-Emitt	er Voltag	ge, V _{BE} -	- V	1.2

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